

Sandwich communication extensions XN07 Part number 88974250



- Exchange of input/output state with FBD programming
- Only compatible with Smart controllers
- Periodic exchanges with max. 6 XN06 extensions
- Automatic recognition of number of slaves

Type	Description	Supply
88974250 XN07	6-word "exchange unit" communication extension	Via the 24 V DC controller

Certifications	UL, CSA GL: except for 88 970 32x (pending)
Conformity with the low voltage directive	In accordance with 73/23/EEC:
	EN (IEC) 61131-2 (Open equipment)
Conformity with the EMC directive	In accordance with 89/336/EEC: EN (IEC) 61131-2 (Zone B) EN (IEC) 61000-6-2, EN (IEC) 61000-6-3 (*) EN (IEC) 61000-6-4 (*) Except configuration (88 970 1.1 or 88 970 1.2) + (88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure
Earthing	Not included
Protection rating	In accordance with IEC/EN 60529: IP40 on front panel IP20 on terminal block
Overvoltage category	3 in accordance with IEC/EN 60664-1
Pollution	Degree: 2 in accordance with IEC/EN 61131-2
Max operating Altitude	Operation: 2000 m Transport: 3048 m
Mechanical resistance	Immunity to vibrations IEC/EN 60068-2-6, test Fc Immunity to shock IEC/EN 60068-2-27, test Ea
Resistance to electrostatic discharge	Immunity to ESD IEC/EN 61000-4-2, level 3
Resistance to HF interference	Immunity to radiated electrostatic fields IEC/EN 61000-4-3 Immunity to fast transients (burst immunity) IEC/EN 61000-4-4, level 3 Immunity to shock waves IEC/EN 61000-4-5 Radio frequency in common mode IEC/EN 61000-4-6, level 3 Voltage dips and breaks (AC) IEC/EN 61000-4-11 Immunity to damped oscillatory waves IEC/EN 61000-4-12
Conducted and radiated emissions	Class B (*) in accordance with EN 55022/11 group 1 (*) Except configuration (88 970 1.1 or 88 970 1.2) + (88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure)
Operating temperature	-20 →+55°C (+40°C in a non-ventilated enclosure) in accordance with IEC/EN 60068-2-1 and IEC/EN 60068-2-2
Storage temperature	-40 →+70°C in accordance with IEC/EN 60068-2-1 and IEC/EN 60068-2-2
Relative humidity	95% max. (no condensation or dripping water) in accordance with IEC/EN 60068-2-30
Mounting	On symmetrical DIN rail, 35 x 7.5 mm and 35 x 15 mm, or on panel (2 x Ø 4 mm)
Screw terminals connection capacity	Flexible wire with ferrule = 1 conductor: 0.25 to 2.5 mm ² (AWG 24AWG 14) 2 conductors 0.25 to 0.75 mm ² (AWG 24AWG 18) Semi-rigid wire = 1 conductor: 0.2 to 2.5 mm ² (AWG 25AWG 14) Rigid wire = 1 conductor: 0.2 to 2.5 mm ² (AWG 25AWG 14) 2 conductors 0.2 to 1.5 mm ² (AWG 25AWG 16) Tightening torque = 0.5 N.m (4.5 lb-in) (tighten using screwdriver diam. 3.5 mm)

"Exchange unit" characteristics	
*** TRADUCTION MANQUANTE ***	*** TRADUCTION MANQUANTE ***
General characteristics	

*** TRADUCTION MANQUANTE ***			
Certifications	UL, cUL pending		
Earthing	Internal link between electronic mass and equipment mass		
	Refer to the quick reference guide supplied with the product		
Operating temperature	-20 →+55 °C (+40 °C in a non-ventilated enclosure) in accordance with to IEC/EN 60068-2-1 and IEC/EN 60068-2-2		
Cable length	Maximum network length: 1000 m		
	(max. 9600 bauds, AWG 26)		
Pull-up and Pull-down resistance	Polarised line with 470 Ω resistance (included in product)		
Communication parameters			
*** TRADUCTION MANQUANTE ***			
Type of link	2 or 4-wire; RTU or ASCII		
Transmission rate (Bauds)	1200, 2400, 4800, 9600, 19200, 28800, 38400, 57600		
Parity	None; even; odd		
Addressing	XN07: 7 →247 XN06: 1 →6		
Characteristics of evaluation	A1100. 1 -70		
Characteristics of exchanges			
*** TRADUCTION MANQUANTE ***			
Function blocks programming			
Read-words	1 to 6, depending on the number of XN06 (1 XN06: 6 words, 2 XN		
Write-words	1 to 6, depending on the number of XN06 (1 XN06: 6 words, 2 XN	l06: 3 words, 3 XN06: 2 words, 4, 5 or 6 XN06: 1 word)	
"Status" words	1 (state of XN06, connected - non-connected)		
Clock synchronise bit	Date and time update bit XN07 → XN06		
Initialisation bit Watch dog bit	Initialisation bit (update of number of slaves connected) 1 per XN06 (0/1 if connected)		
Cycle time	RTU		
	at 1200 bauds: with 6 XN06: < 3.7 s		
	at 1200 bauds: with 1 XN06: < 1 s		
	at 57600 bauds: with 6 XN06: < 0.2 s		
	ASCII		
	at 1200 bauds: with 6 XN06: < 5.7 s		
	at 1200 bauds: with 1 XN06: < 1.5 s		
	at 57600 bauds: with 6 XN06: < 0.2 s		
Processing characteristics of CB, CD, XD & XB	product types		
LCD display	CD, XD: Display with 4 lines of 18 characters		
Programming method	Ladder or FBD/SFC (Grafcet)		
Program size	Ladder: 120 lines		
	FBD:		
	CB, CD: 350 typical blocks XB, XD: 700 typical blocks		
Program memory	Flash EEPROM		
Removable memory	EEPROM		
	EEPROM 368 bits/200 words		
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Response time with function blocks programming	Configurable in increments of 10 ms 50 ms min. up to 255 ms State 0 \rightarrow 1 (50/60 Hz)		Configurable in increments of 10 ms 50 ms min. up to 255 ms State $0 \rightarrow 1 (50/60 \text{ Hz})$
Maximum counting frequency	In accordance with cycle time (Tc) and input 1/ ((2 x Tc) + Tr)	response time (Tr) :	In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr)
Sensor type	Contact or 3-wire PNP		Contact or 3-wire PNP
Input type	Resistive		Resistive
Isolation between power supply and inputs	None		None
Isolation between inputs	None		None
Protection against polarity inversions	Yes		Yes
Status indicator	On LCD screen for CD and XD		On LCD screen for CD and XD
Characteristics of relay outputs common to the e	ntire range		
Max. breaking voltage	5 →30 V DC 24 →250 V AC		
Breaking current	CB-CD-XD10-XB10-XR06-XR10: 8 A XD26-XB26: 8 x 8 A relays, 2 x 5 A relays XE10: 4 x 5 A relays XR14: 4 x 8 A relays, 2 x 5 A relays		
Electrical durability for 500 000 operating cycles	Utilization category DC-12: 24 V, 1.5 A Utilization category DC-13: 24 V (L/R = 10 ms), 0.6 A Utilization category AC-12: 230 V, 1.5 A Utilization category AC-15: 230 V, 0.9 A		
Max. Output Common Current	12 A for O8, O9, OA		
Minimum switching capacity	10 mA (at minimum voltage of 12 V)		
Minimum load	12 V, 10 mA		
Maximum rate	Off load: 10 Hz		
Mechanical life	At operating current: 0.1 Hz 10,000,000 (operations)		
Voltage for withstanding shocks	In accordance with IEC/EN 60947-1 and IEC/	FN 60664-1: 4 k\/	
Response time	Make 10 ms	LIT 00004-1. 4 KV	
Built-in protections	Release 5 ms Against short-circuits: None		
	Against overvoltages and overloads: None		
Status indicator	On LCD screen for CD and XD		
Characteristics of product with DC power supplie	ed .		
Supply			
Nominal voltage	12 V DC	24 V DC	
Operating limits	-13% / +20%	-20% / +25%	
	or 10.4 V DC→14.4 V DC (including ripple)	or 19.2 V DC→30 V	
Immunity from micro power cuts Max. absorbed power	≤ 1 ms (repetition 20 times) CB12 with solid state outputs: 1.5 W	≤ 1 ms (repetition 20	rith solid state outputs - XD10-XB10 with solid state outputs: 3 W
	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela	ay outputs: 4 W did not state outputs: 5 W did state outputs: 5 W day outputs - XD26 with relay outputs: 6 W
	CD12: 1.5 W CD20: 2.5 W	XD10-XB10 with rela XD26-XB26 with soli	ay outputs: 4 W did state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W
Protection against polarity inversions	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext	ay outputs: 4 W did state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W
	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W did state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY)	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W did state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W
Protection against polarity inversions	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W d d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA	XD10-XB10 with relative XD26-XB26 with solic CB20-CD20 with relative XD10-XB10 with extra XD26-XB26 with extra XD2	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr)	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz)
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr)
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr)	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 → 2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 → 2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None None	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None None
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG)	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG)	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10 CB20-CD20-XB26-XD26	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10 CB20-CD20-XB26-XD26 Inputs used as analogue inputs	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IE	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10 CB20-CD20-XB26-XD26 Inputs used as analogue inputs Measurement range	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IE	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IE 6 inputs IB →IG
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10 CB20-CD20-XB26-XD26 Inputs used as analogue inputs Measurement range Input impedance	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IE 6 inputs IB →IG	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IE 6 inputs IB →IG
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10 CB20-CD20-XB26-XD26 Inputs used as analogue inputs Measurement range Input impedance Input voltage	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IE 6 inputs IB →IG (0 →10 V) or (0 →V power supply) 14 kΩ 14.4 V DC max.	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IE 6 inputs IB →IG (0 →10 V) or (0 →V power supply) 12 kΩ 30 V DC max.
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10 CB20-CD20-XB26-XD26 Inputs used as analogue inputs Measurement range Input impedance Input voltage Value of LSB	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IG (0 →10 V) or (0 →V power supply) 14 kΩ 14.4 V DC max. 14 mV, 4 mA Common mode 10 bits at max. input voltage	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IG (0 →10 V) or (0 →V power supply) 12 kΩ 30 V DC max. 29 mV, 4 mA Common mode 10 bits at max. input voltage
Protection against polarity inversions Digital inputs (I1 to IA and IH to IY) Input voltage Input current Input impedance Logic 1 voltage threshold Making current at logic state 1 Logic 0 voltage threshold Release current at logic state 0 Response time Maximum counting frequency Sensor type Conforming to IEC/EN 61131-2 Input type Isolation between power supply and inputs Isolation between inputs Protection against polarity inversions Status indicator Analogue or digital inputs (IB to IG) CB12-CD12-XD10-XB10 CB20-CD20-XB26-XD26 Inputs used as analogue inputs Measurement range Input impedance Input voltage Value of LSB Input type	CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W Yes 12 V DC (-13% / +20%) 3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC 5.3 mA @ 14.4 VDC 2.7 kΩ ≥ 7 V DC ≥ 2 mA ≤ 3 V DC < 0.9 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 Inputs I3 to IA & IH to IY: In accordance with input response time (Tr): 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IG (0 →10 V) or (0 →V power supply) 14 kΩ 14.4 V DC max. 14 mV, 4 mA Common mode	XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD10-XB10 with ext XD26-XB26 with ext Yes	ay outputs: 4 W d state outputs: 5 W ay outputs - XD26 with relay outputs: 6 W ension: 8 W ension: 10 W 24 V DC (-20% / +25%) 2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC 4.0 mA @ 30.0 VDC 7.4 kΩ ≥ 15 V DC ≥ 2.2 mA ≤ 5 V DC < 0.75 mA 1 →2 cycle times Inputs I1 & I2: Ladder (1 kHz) & FBD (up to 6 kHz) Inputs I3 to IA & IH to IY: In accordance with cycle time (Tc) and input response time (Tr) : 1/ ((2 x Tc) + Tr) Contact or 3-wire PNP Type 1 Resistive None None None Yes On LCD screen for CD and XD 4 inputs IB →IE 6 inputs IB →IG (0 →10 V) or (0 →V power supply) 12 kΩ 30 V DC max. 29 mV, 4 mA Common mode

		www.ciouzet.com
Accuracy at 25°C	± 5%	± 5%
Accuracy at 55°C	± 6.2%	± 6.2%
Repeat accuracy at 55 °C	± 2%	± 2%
Isolation between analogue channel and power supply	Nana	None
isolation between analogue channel and power supply	None	None
Cable length	10 m maximum, with shielded cable (sensor not isolated)	10 m maximum, with shielded cable (sensor not isolated)
· ·		
Protection against polarity inversions	Yes	Yes
Potentiometer control	2.2 kΩ/0.5 W (recommended)	2.2 kΩ/0.5 W (recommended)
1 Storthornotor Control		,
	10 kΩ max.	10 kΩ max.
Inputs used as digital inputs		
inputs used as digital inputs		
Input voltage	12 V DC (-13% / +20%)	24 V DC (-20% / +25%)
	` '	` '
Input current	0.7 mA @ 10.44 VDC	1.6 mA @ 19.2 VDC
	0.9 mA @ 12.0 VDC	2.0 mA @ 24.0 V DC
	1.0 mA @ 14.4VDC	2.5 mA @ 30.0 VDC
Input impedance	14 kΩ	12 kΩ
Logic 1 voltage threshold	≥7 V DC	≥ 15 VDC
Making current at logic state 1	≥ 0.5 mA	≥ 1.2 mA
Logic 0 voltage threshold	≤3 V DC	≤5 V DC
Release current at logic state 0	≤ 0.2 mA	≤ 0.5 mA
· ·		
Response time	1 →2 cycle times	1 →2 cycle times
Maximum counting fraguency	In accordance with evals time (To) and input response time (Tr)	In accordance with evale time (Te) and input response time (Tr) :
Maximum counting frequency	In accordance with cycle time (Tc) and input response time (Tr):	In accordance with cycle time (Tc) and input response time (Tr):
	1/ ((2 x Tc) + Tr)	1/ ((2 x Tc) + Tr)
Consortius	Contact on 2 using DND	
Sensor type	Contact or 3-wire PNP	Contact or 3-wire PNP
Conforming to IEC/EN 61131-2	Type 1	Type 1
	**	• •
Input type	Resistive	Resistive
Isolation between power supply and inputs	None	None
Isolation between inputs	None	None
Protection against polarity inversions	Yes	Yes
Status indicator	On LCD screen for CD and XD	On LCD screen for CD and XD
Characteristics of relay outputs common to the e	ntire range	
2		
Max. breaking voltage	5 →30 V DC	
	24 →250 V AC	
M. O. I. I.O		
Max. Output Common Current	12A for O8, O9, OA	
Breaking current	CB-CD-XD10-XB10-XR06-XR10: 8 A	
	XD26-XB26: 8 x 8 A relays, 2 x 5 A relays	
	XE10: 4 x 5 A relays	
	XR14: 4 x 8 A relays, 2 x 5 A relays	
Electrical durability for 500 000 operating cycles	Utilization category DC-12: 24 V, 1.5 A	
	Utilization category DC-13: 24 V (L/R = 10 ms), 0.6 A	
	Utilization category AC-12: 230 V, 1.5 A	
	Utilization category AC-15: 230 V, 0.9 A	
Minimum switching capacity	10 mA (at minimum voltage of 12 V)	
	10 IIIA (at IIIIIIIIII voitage of 12 v)	
Minimum load	12 V, 10 mA	
Manifestoria		
Maximum rate	Off load: 10 Hz	
	At operating current: 0.1 Hz	
Mechanical life	10,000,000 (operations)	
Mechanical life		
Voltage for withstanding shocks	In accordance with IEC/EN 60947-1 and IEC/EN 60664-1: 4 kV	
· ·	Malia 40 ma	
Response time	Make 10 ms	
	Release 5 ms	
Duilt in protections	Against short sirevits None	
Built-in protections	Against short-circuits: None	
	Against overvoltages and overloads: None	
Status indicator	On LCD screen for CD and XD	
Otatus mulcator	OH LOD SUICCITION OD AND AD	
Digital / PWM solid state output		
PWM solid state output*	CB12: O4	CD12-XD10-XB10: O4
	XD26: O4 →O7	CD20-XD26-XB26: O4 →O7
		ODZU ADZU-ADZU. OT -OI
* Only available with "FBD" programming language	* Only available with "FBD" programming language	
Breaking voltage	10.4 →30 V DC	19.2 →30 V DC
Nominal voltage	12-24 VDC	24 V DC
Nominal current	0.5 A	0.5 A
Max. breaking current	0,625 A	0,625 A
	*	
Voltage drop	≤ 2 V for I = 0.5 A (at state 1)	≤ 2 V for I = 0.5 A (at state 1)
Response time	Make ≤ 1 ms	Make ≤ 1 ms
	Release ≤ 1 ms	Release ≤ 1 ms
Built-in protections	Against overloads and short-circuits: Yes	Against overloads and short-circuits: Yes
	Against overvoltages (*) : Yes	Against overvoltages (*): Yes
	Against inversions of power supply: Yes	Against inversions of power supply: Yes
	(*) In the absence of a volt-free contact between the logic	(*) In the absence of a volt-free contact between the logic
	controller output and the load	controller output and the load
	•	·
Min. load	1 mA	1 mA
Maximum incandescent load	0,2 A / 12 V DC	0,1 A / 24 V DC
	0,1 A / 24 V DC	5,, E1 Y DO
Calvania icalation		No
Galvanic isolation	No	No
PWM frequency	14.11 Hz	14.11 Hz
	56.45 Hz	56.45 Hz
	112.90 Hz	112.90 Hz
	225.80 Hz	225.80 Hz
	451.59 Hz	451.59 Hz
	1806.37 Hz	1806.37 Hz
PWM cyclic ratio		
PWM cyclic ratio	0 →100% (256 steps for CD, XD and 1024 steps for XA)	$0 \rightarrow 100\%$ (256 steps for CD, XD and 1024 steps for XA)
PWM accuracy at 120 Hz	< 5% (20% →80%) load at 10 mA	< 5% (20% →80%) load at 10 mA
	` '	,
PWM accuracy at 500 Hz	< 10% (20% →80%) load at 10 mA	< 10% (20% →80%) load at 10 mA
Status indicator	On LCD screen for XD	On LCD screen for CD and XD
Tanao maioator		00.001101 05 a.lu /\b

Designation

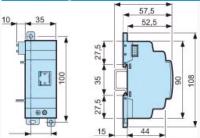
RJ45 tee-joint with 20 cm cable

EOL ferrules, RC 120 ö 1 nF (pack of 2)

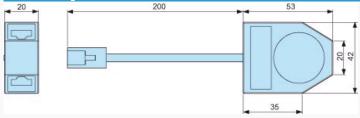
RJ45 wiring kit (2 tees, 2 ferrules, 1 x 4-pair FTP cable, 3 m)

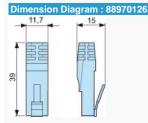
88970125 88970126 88970127

Dimension Diagram : XN07

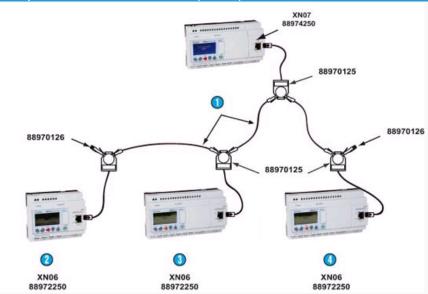


Dimension Diagram: 88970125





: Example with three slaves and accessories (two-wire)



- RJ45/RJ45 "Cat 5E" 100 Ω FTP, 4 pairs (available in RJ45 wiring kit part no.: 88970127)
- 2 XN06 Modbus slave 1
- 3 XN06 Modbus slave 2
- XN06 Modbus slave 3